Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic and metal
Overall Length:
0.063 inches
Overall Height:
0.008 inches
Overall Width:
0.063 inches
Function For Which Designed:
Rectifier
Mounting Method:
Press fit
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
150.0 working peak reverse voltage and 150.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
125.00 amperes forward current, average preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
1 bonding pad and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0